

2N5943

The RF Line

NPN SILICON HIGH-FREQUENCY TRANSISTOR

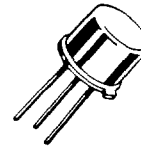
... designed specifically for broadband applications requiring low cross-modulation distortion and low-noise figure. Characterized for use in CATV applications.

- Low Noise Figure – @ $f = 200$ MHz
 NF (Narrowband) = 3.4 dB (Typ)
 NF (Broadband) = 6.8 dB (Typ)
- High Current-Gain – Bandwidth Product –
 $f_T = 1200$ MHz (Min) @ $I_C = 50$ mAcd
- Completely Characterized with s and y -Parameters

1.2 GHz – 50 mAcd

NPN SILICON
HIGH-FREQUENCY
TRANSISTOR

NPN SILICON

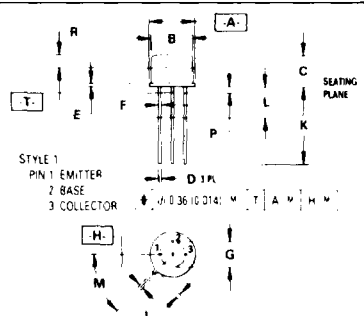
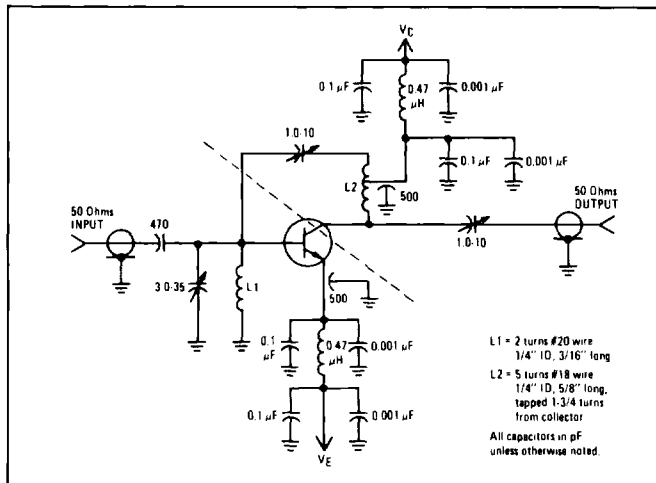


***MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	30	Vdc
Collector-Base Voltage	V_{CBO}	40	Vdc
Emitter-Base Voltage	V_{EBO}	3.5	Vdc
Collector Current – Continuous	I_C	400	mAcd
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 5.7	Watt mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	3.5 0.02	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

*Indicates JEDEC Registered Data.

FIGURE 1 – NARROW-BAND TEST CIRCUIT



- NOTES**
- 1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
 - 2 CONTROLLING DIMENSION INCH
 - 3 DIMENSION J MEASURED FROM DIMENSION A MAXIMUM
 - 4 DIMENSION B SHALL NOT VARY MORE THAN 0.25 (0.010) IN ZONE R THIS ZONE CONTROLLED FOR AUTOMATIC HANDLING
 - 5 DIMENSION F APPLIES BETWEEN DIMENSION P AND L DIMENSION D APPLIES BETWEEN DIMENSION L AND K MINIMUM LEAD DIAMETER IS UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.51	9.35	0.335	0.370
B	7.75	8.50	0.305	0.335
C	6.10	6.60	0.240	0.260
D	0.41	0.53	0.016	0.021
E	0.23	1.04	0.009	0.041
F	0.41	0.48	0.016	0.019
G	5.08 BSC			
H	0.72	0.86	0.028	0.034
J	0.74	1.14	0.029	0.045
K	12.70	19.05	0.500	0.750
L	6.35			
M	45 BSC		45 BSC	
N	1.27		0.050	
R	2.54	0.100		

CASE 79-04
TO-205AD
(TO-39)

2N5943

*ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage ($I_C = 5.0 \text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	30	—	—	Vdc
Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{Adc}$, $I_E = 0$)	$V_{(BR)CBO}$	40	—	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 100 \mu\text{Adc}$, $I_C = 0$)	$V_{(BR)EBO}$	3.5	—	—	Vdc
Collector Cutoff Current ($V_{CE} = 20 \text{ Vdc}$, $I_B = 0$)	I_{CEO}	—	—	50	μAdc
Collector Cutoff Current ($V_{CB} = 15 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	—	10	μAdc

ON CHARACTERISTICS

DC Current Gain ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$)	h_{FE}	25	—	300	—
Collector-Emitter Saturation Voltage ($I_C = 100 \text{ mAdc}$, $I_B = 10 \text{ mAdc}$)	$V_{CE(sat)}$	—	0.15	0.2	Vdc
Base-Emitter Saturation Voltage ($I_C = 100 \text{ mAdc}$, $I_B = 10 \text{ mAdc}$)	$V_{BE(sat)}$	—	0.88	1.0	Vdc

DYNAMIC CHARACTERISTICS

Current-Gain – Bandwidth Product (Figure 2) ($I_C = 25 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 200 \text{ MHz}$) ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 200 \text{ MHz}$) ($I_C = 100 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 200 \text{ MHz}$)	f_T	1000 1200 1000	1350 1550 1425	— 2400 —	MHz
Collector-Base Capacitance (Figure 5) ($V_{CB} = 30 \text{ Vdc}$, $I_E = 0$, $f = 100 \text{ kHz}$)	C_{cb}	1.0	1.6	2.5	pF
Emitter-Base Capacitance (Figure 5) ($V_{EB} = 0.5 \text{ Vdc}$, $I_C = 0$, $f = 100 \text{ kHz}$)	C_{eb}	—	8.4	15	pF
Small-Signal Current Gain ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	h_{fe}	25	—	350	—
Collector-Base Time Constant ($I_E = 50 \text{ mAdc}$, $V_{CB} = 15 \text{ Vdc}$, $f = 31.8 \text{ MHz}$)	$r_b C_c$	—	5.5	—	ps
Noise Figure ($I_C = 30 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 200 \text{ MHz}$) (Figure 1) ($I_C = 35 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 200 \text{ MHz}$) (Figures 6, 11, 14) (1)	NF	—	3.4 6.8	— 8.0	dB

FUNCTIONAL TEST

Common-Emitter Amplifier Power Gain ($I_C = 10 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 200 \text{ MHz}$) (Figure 1) ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $f = 250 \text{ MHz}$) (Figure 6)	G_{pe}	— 7.0	11.4 7.6	— —	dB
Intermodulation Distortion (Figure 7) ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $V_{out} = +50 \text{ dBmV}$)	IM	—	—	-50	dB
Cross Modulation Distortion (Figure 8) ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $V_{out} = +40 \text{ dBmV}$) ($I_C = 50 \text{ mAdc}$, $V_{CE} = 15 \text{ Vdc}$, $V_{out} = +50 \text{ dBmV}$)	XM	— —	-67 -45	— -42	dB

*Indicates JEDEC Registered Data.

(1) Includes noise figure of post amplifier and matching pad.

FIGURE 2 – CURRENT-GAIN – BANDWIDTH PRODUCT

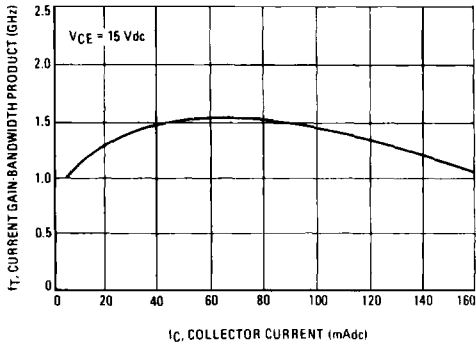


FIGURE 3 – COLLECTOR-BASE TIME CONSTANT

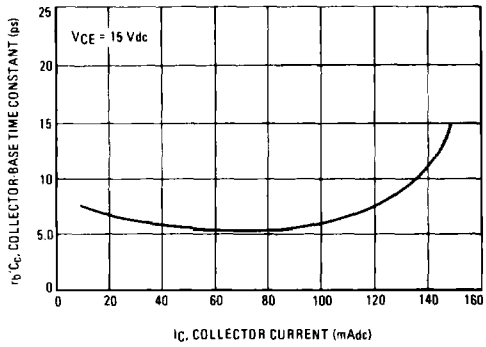


FIGURE 4 – SATURATION VOLTAGES

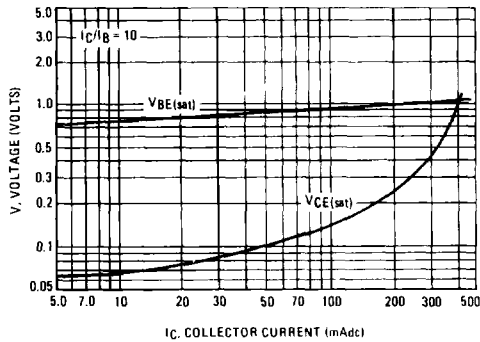


FIGURE 5 – CAPACITANCES versus REVERSE VOLTAGE

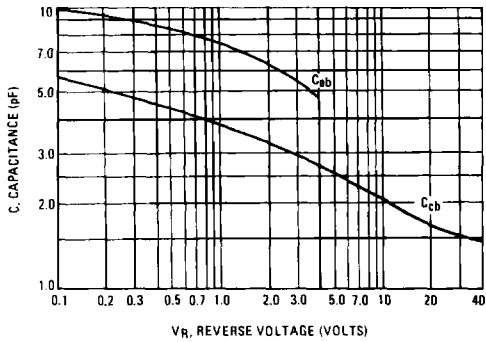
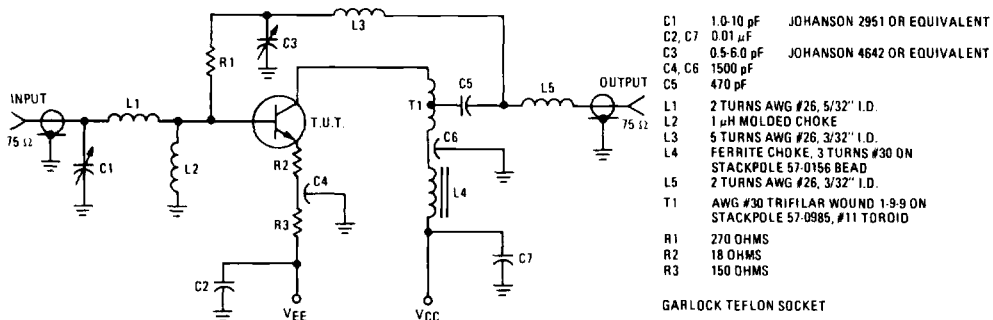


FIGURE 6 – BROADBAND TEST CIRCUIT



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FIGURE 7 – CROSS-MODULATION DISTORTION versus COLLECTOR CURRENT

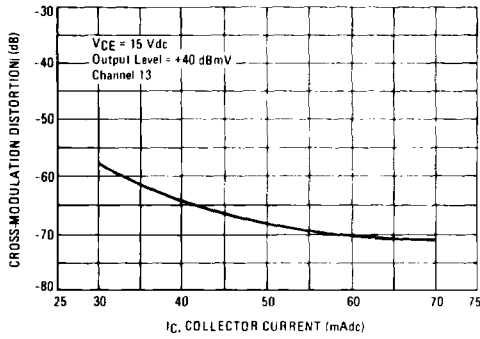


FIGURE 8 – CROSS-MODULATION DISTORTION versus OUTPUT LEVEL

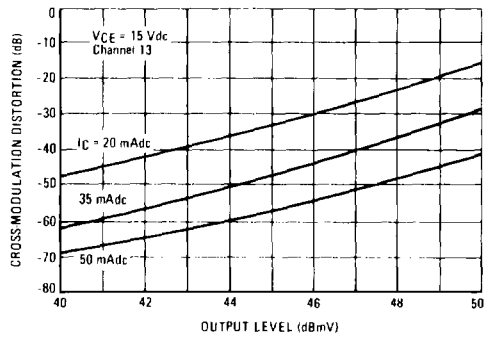


FIGURE 9 – NARROWBAND NOISE FIGURE versus COLLECTOR CURRENT

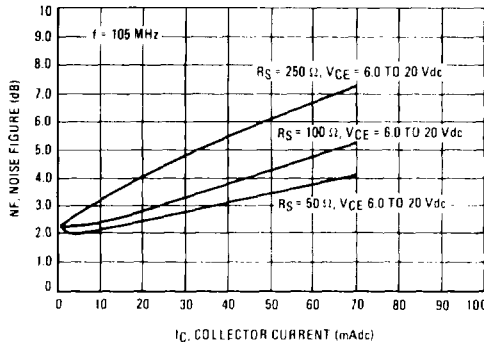


FIGURE 10 – NARROWBAND NOISE FIGURE versus COLLECTOR CURRENT

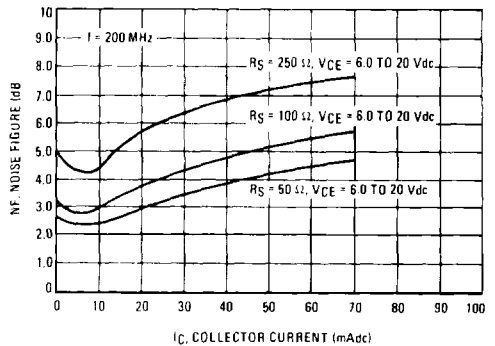


FIGURE 11 – BROADBAND NOISE FIGURE versus COLLECTOR CURRENT

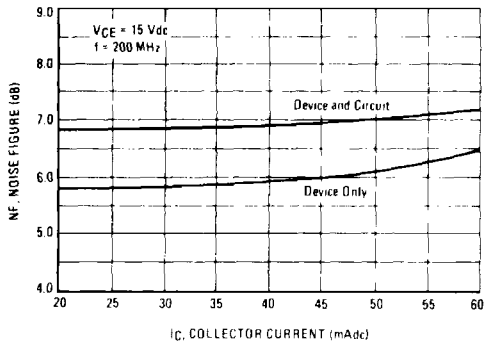


FIGURE 12 – NARROWBAND NOISE FIGURE versus FREQUENCY

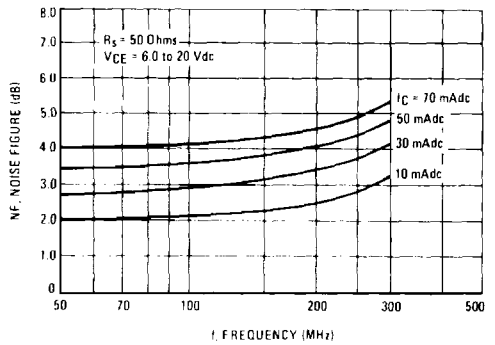


FIGURE 13 – INPUT ADMITTANCE versus FREQUENCY

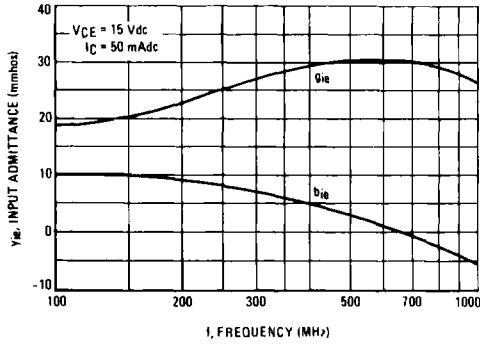


FIGURE 15 – REVERSE TRANSFER ADMITTANCE versus FREQUENCY

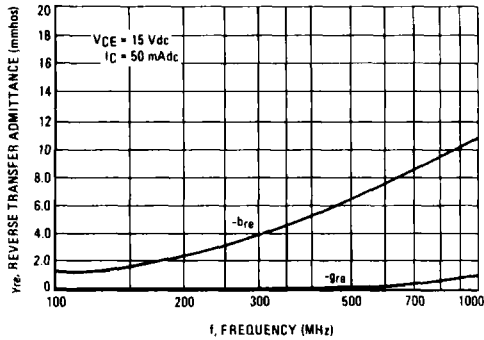


FIGURE 17 – FORWARD TRANSFER ADMITTANCE versus FREQUENCY

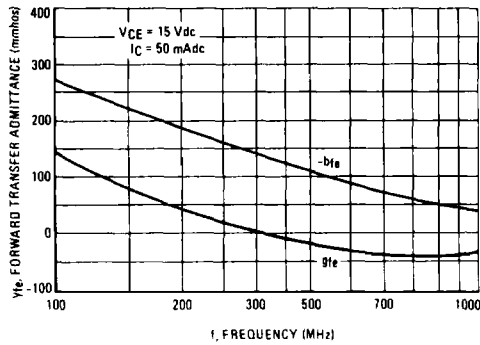


FIGURE 14 – INPUT ADMITTANCE versus COLLECTOR CURRENT

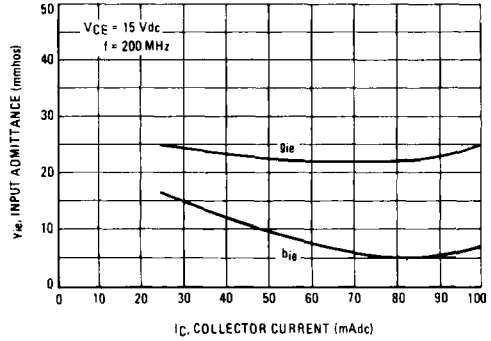


FIGURE 16 – REVERSE TRANSFER ADMITTANCE versus COLLECTOR CURRENT

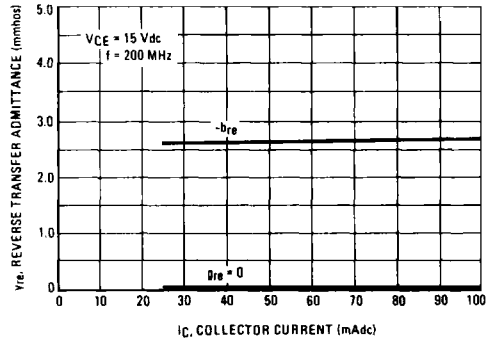
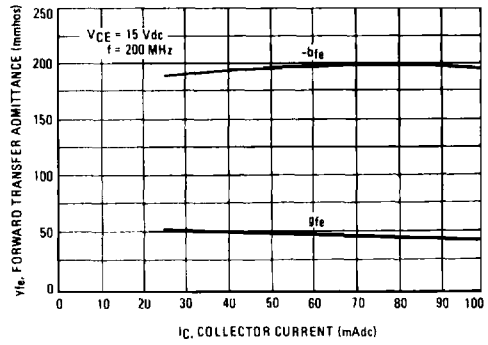


FIGURE 18 – FORWARD TRANSFER ADMITTANCE versus COLLECTOR CURRENT



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FIGURE 19 – OUTPUT ADMITTANCE versus FREQUENCY

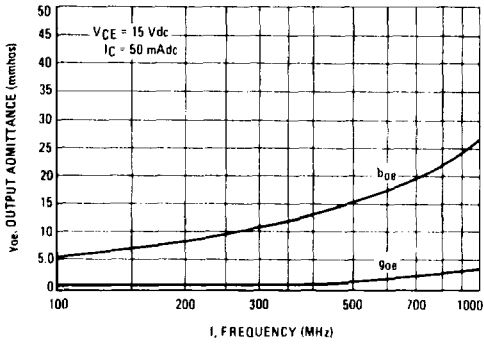


FIGURE 20 – OUTPUT ADMITTANCE versus COLLECTOR CURRENT

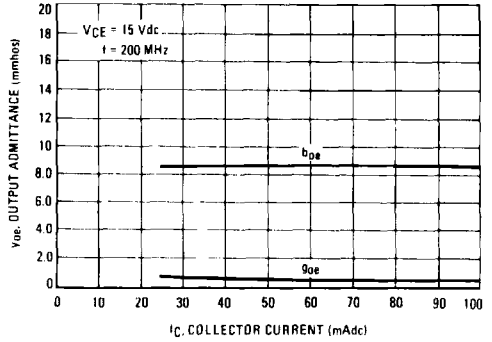


FIGURE 21 – INPUT REFLECTION COEFFICIENT versus FREQUENCY

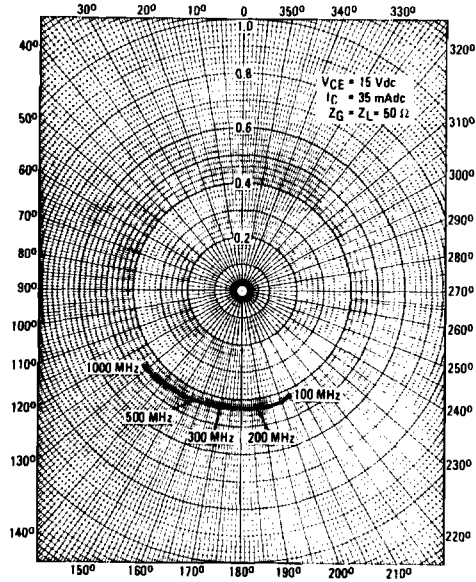


FIGURE 22 – OUTPUT REFLECTION COEFFICIENT versus FREQUENCY

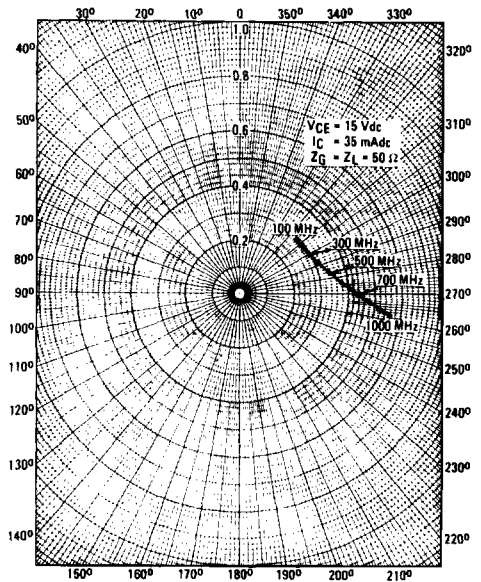


FIGURE 23 – REVERSE TRANSMISSION COEFFICIENT versus FREQUENCY

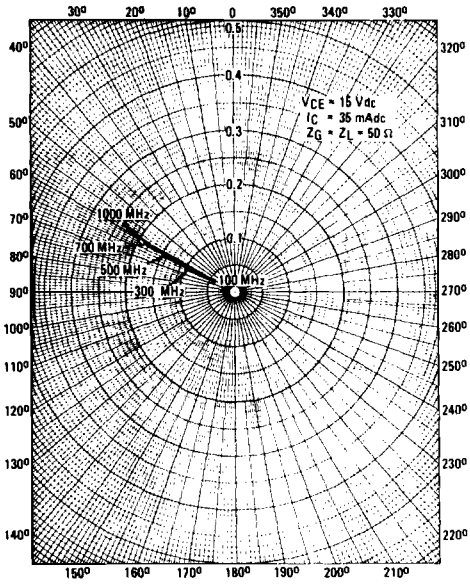
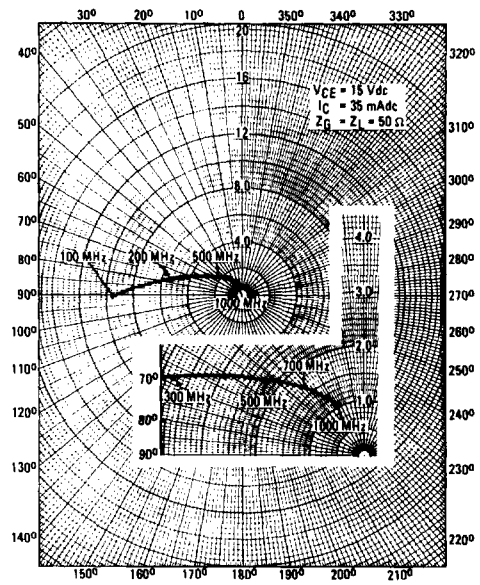


FIGURE 24 – FORWARD TRANSMISSION COEFFICIENT versus FREQUENCY



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FIGURE 25 – INPUT REFLECTION COEFFICIENT AND OUTPUT REFLECTION COEFFICIENT versus FREQUENCY

